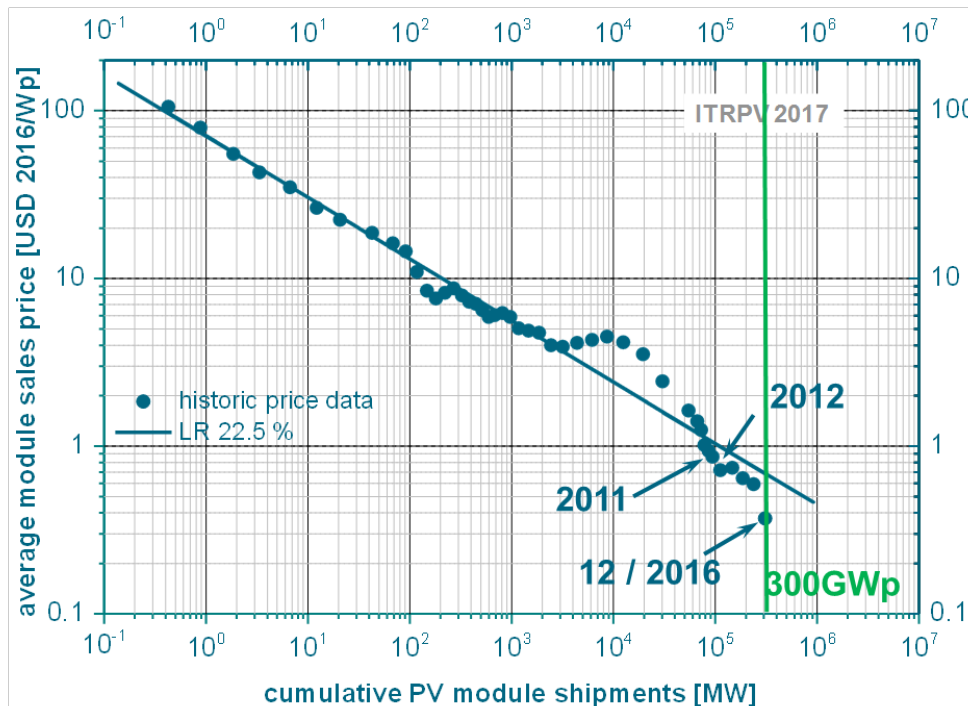


C-Si PV: Manufacturing Trends & Challenges - ITRPV 8th edition update (incl. maturity report)

World Solar Congress | Shanghai, September 5-6, 2017
Dr. Markus Fischer, Hanwha Q Cells, VP R&D Operation

Module Price learning Curve



Shipments /avg. price at years end:

2016: 75 GWp / 0.37 US\$/Wp
 08/2017: 0.35 US\$/Wp

o/a shipment: ≈ 308 GWp
 o/a installation: ≈ 300 GWp

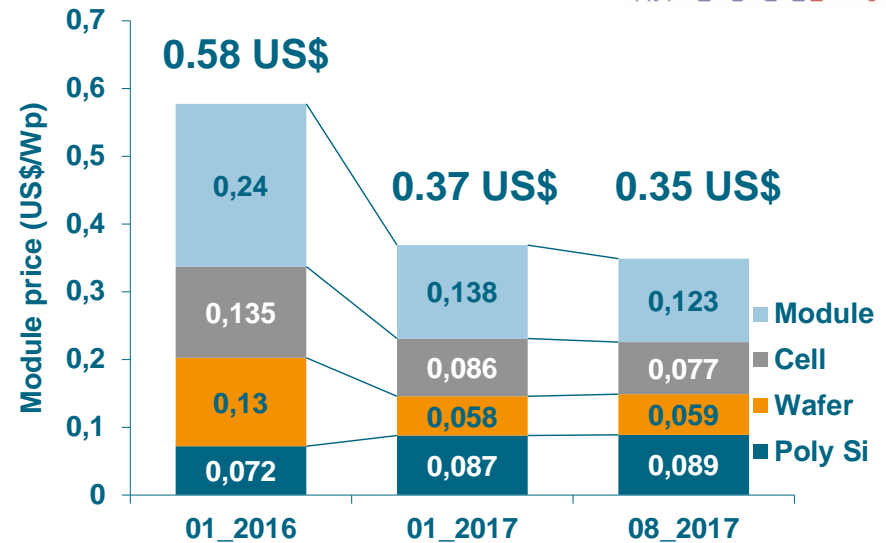
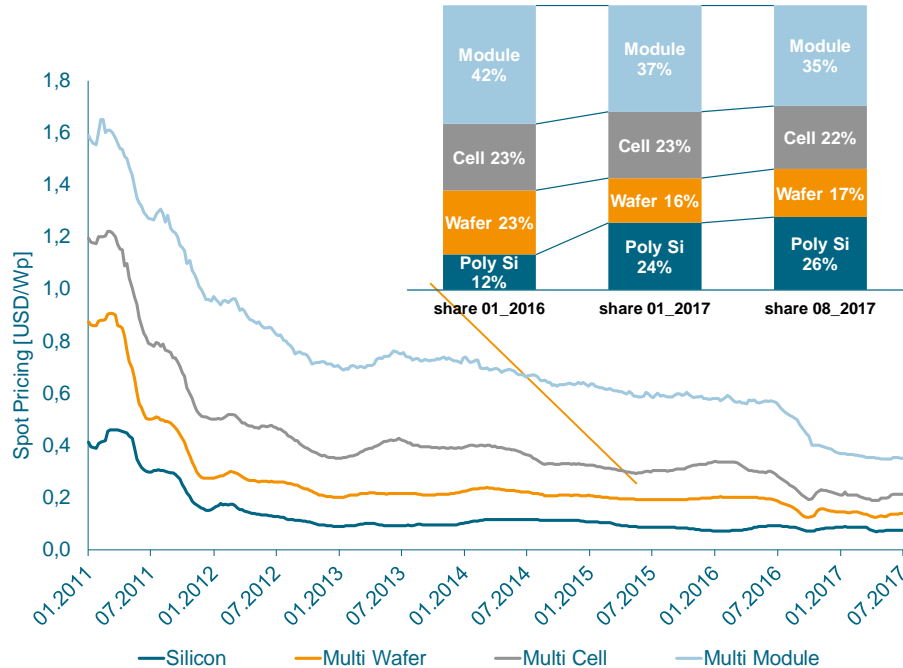
2017 expectation: ≈ 380 GWp

300 GWp landmark was passed!

LR 22.5 % (1976 E 2016)

dramatic price drop due to market situation
 → Comparable to 2011/2012, but faster

Module Price development



Result:

High cost pressure PV - manufacturers

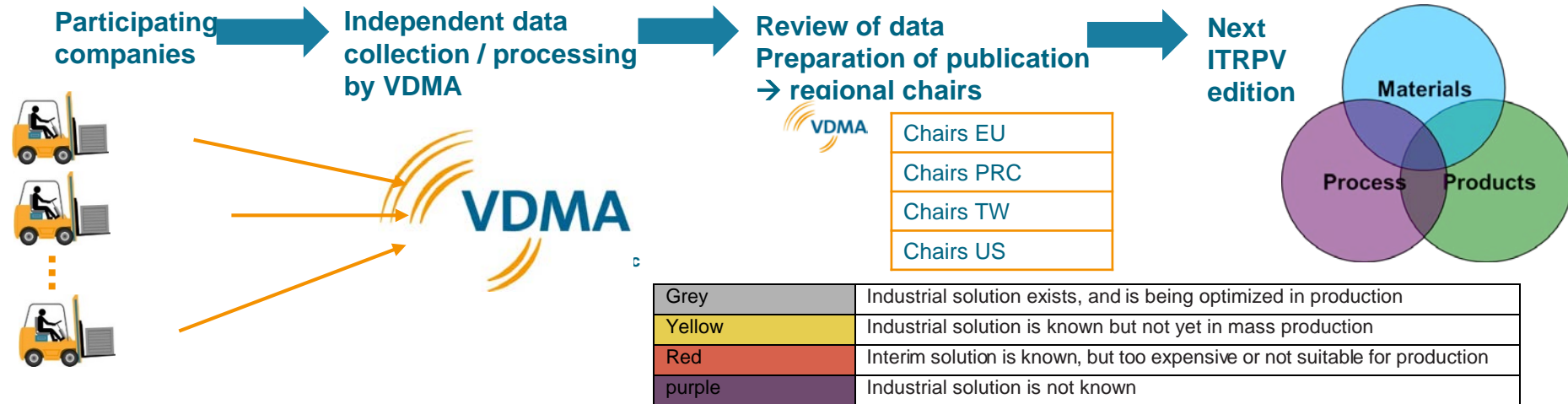
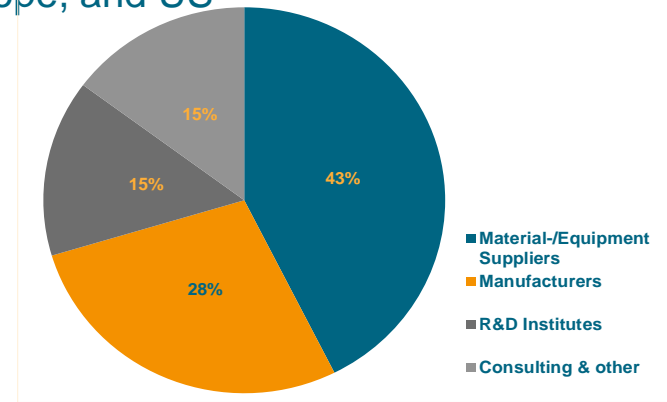
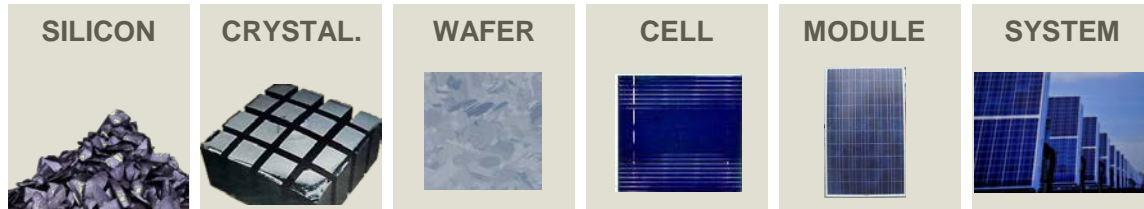
- reduction 01/2011 → 01/2016: ≈ 64 %
- **reduction 01/2016 → 01/2017: ≈ 36 %**
(reduction 01/2011 → 01/2012: ≈ 40 %)
- reduction 01/2017 → 08/2017: ≈ 5% → 0.35US\$

Dramatic price drop in 2016

- Market driven drop
- Poly-Si share increased again (temporary shortage)
- Next price drop expected

ITRPV – Methodology

Working group today includes >50 contributors from Asia, Europe, and US

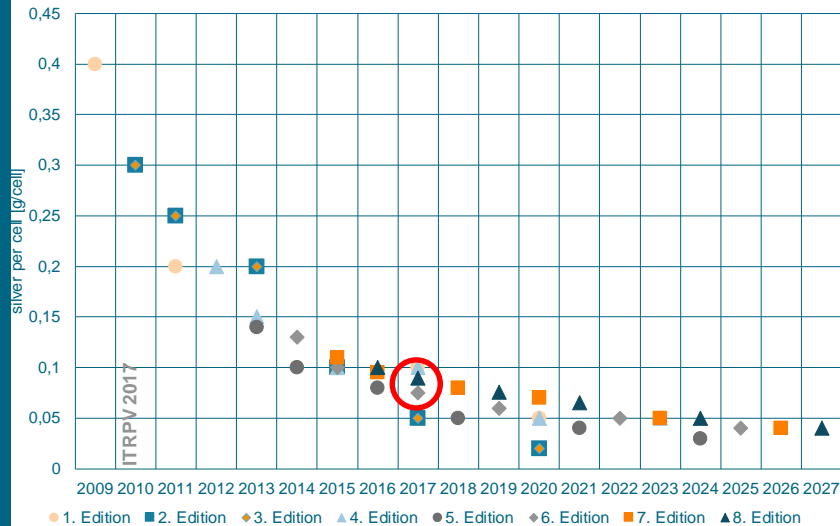


Parameters in main areas are discussed → Diagrams of median values + maturity

Cell – Materials Example: Ag reduction

ITRPV Trend:

Prediction of remaining Ag on c-Si Solar cells → from 2009 to today



Ag reduction will continue

Challenge: increase efficiency, keep quality

90mg remaining Ag are reality

50mg will be reached within 5 years

Measures (new pastes, thinner fingers, multi bus bars, bus bar less, etc...)

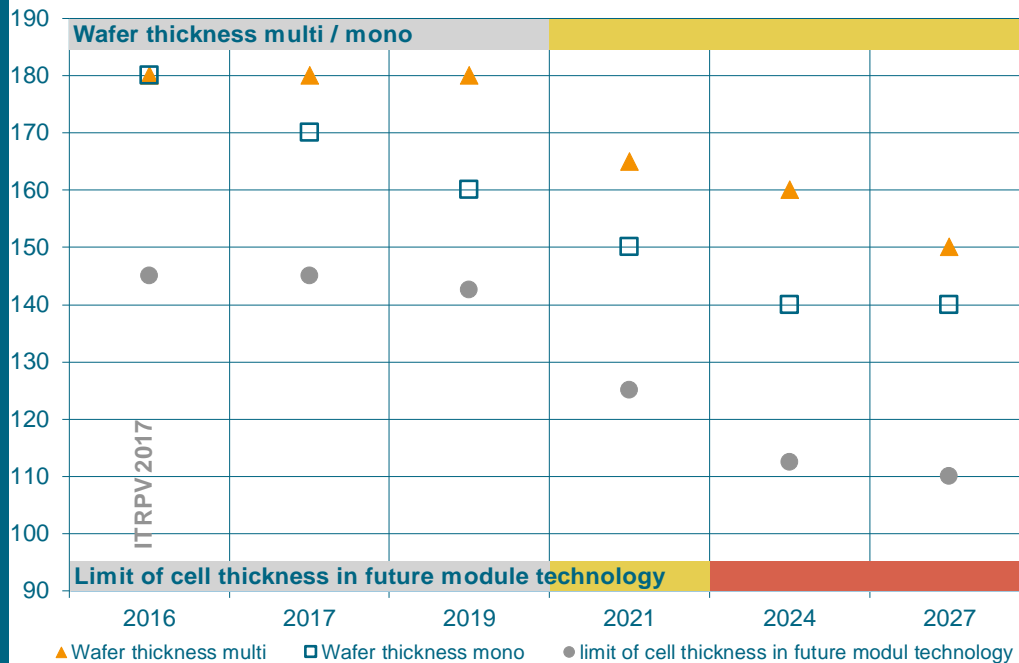
→ **Cost reduction will continue**

→ **Material suppliers have to provide innovation**

→ **Tool suppliers have to support implementation**

Material: Minimum as-cut wafer / cell thickness

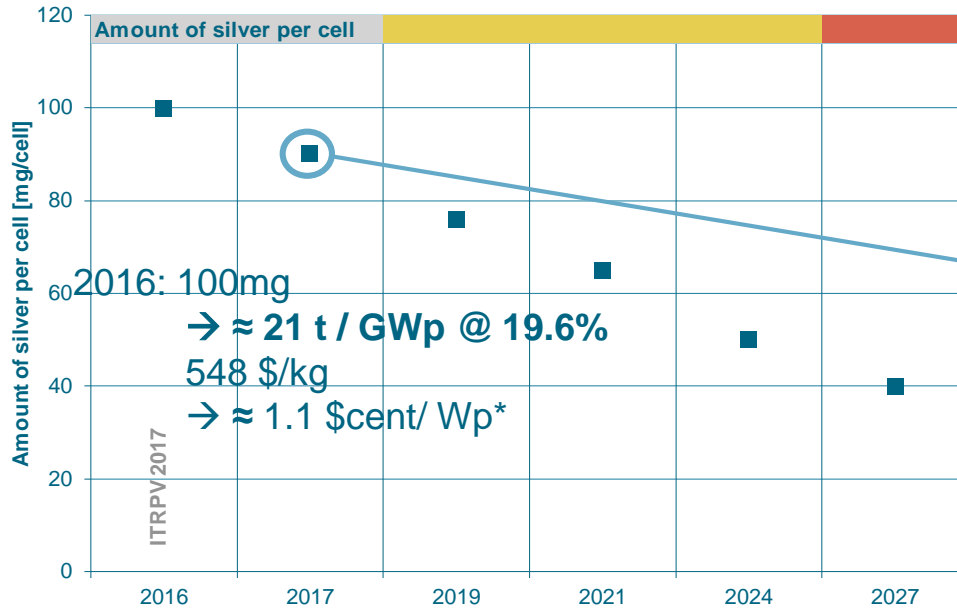
Trend: wafer thickness reduction will materialize



- Reduction to 160µm may appear faster
→ Indicated by grey /yellow marking!
- Down to 140µm will be possible
- Module technology
→ Requires development for < 120µm (red)

Materials – Silver (Ag) per Cell

Ag will remain dominating in c-Si metallization



Ag price is very volatile

- 2016 100 mg
- 2027 40 mg

Maturity report:

90 mg are in mass production (Grey)

Technical solutions for < 90 mg are ready (Yellow)
 → Faster reduction might be possible

No good solutions so far for < 50mg (Red)

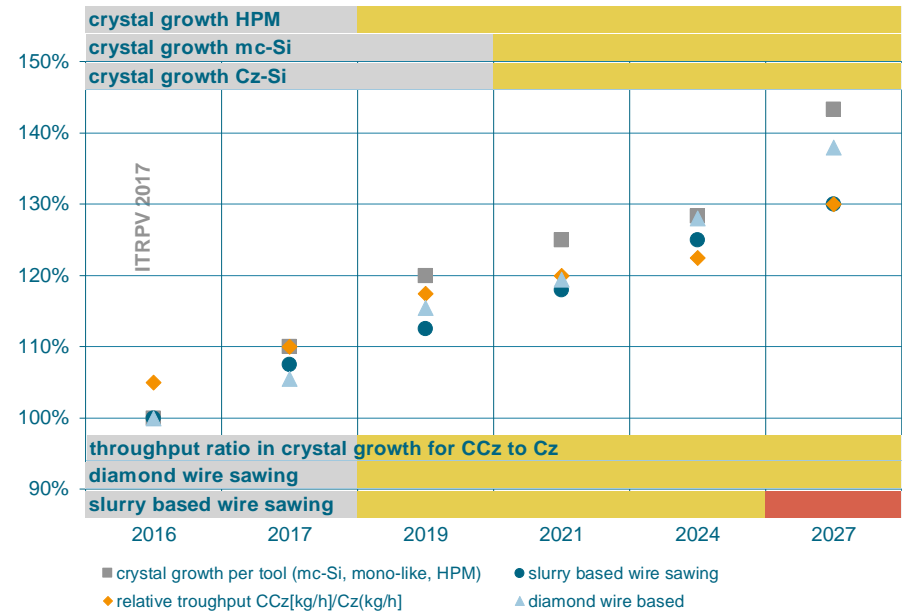
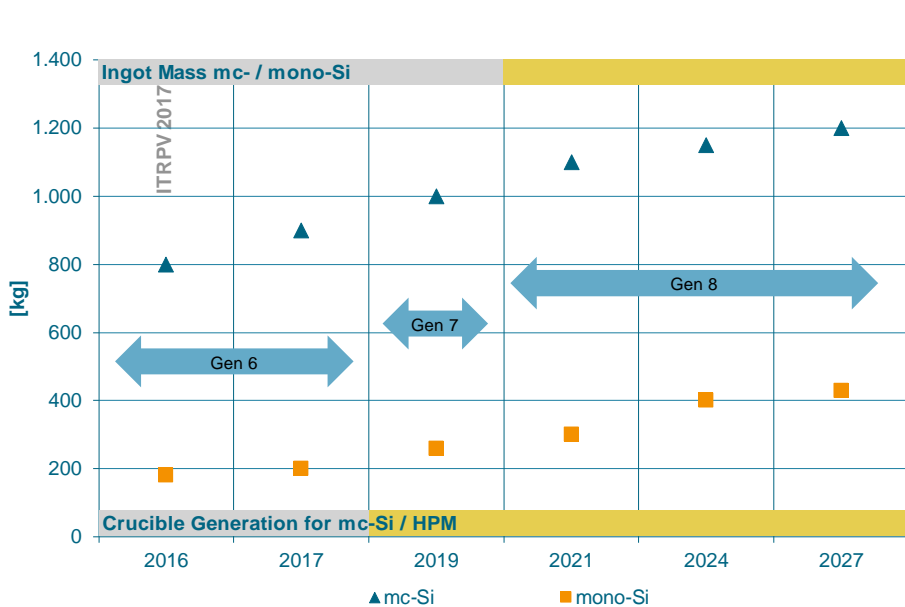
2016:
 Ag accounted for ≈10% of cell conversion price
 → Ag reduction is mandatory and will continue
 → Cu is expected to have 5% market share in 2019

Lead free pastes in production → 2019

* avg. cell efficiency 19.6 % ≈ 4.8 Wp/cell

Processes manufacturing. Ingot mass / throughput

Trend: crystallization ingot size / tool throughput



Casting G6 is standard

→ move to G7/8 may occur faster (yellow coding)

Mono ingot mass 200kg = standard

→ move to 400kg may occur faster (yellow coding)

Crystal growth speed:

→ increase by >30% expected fast (yellow coding)

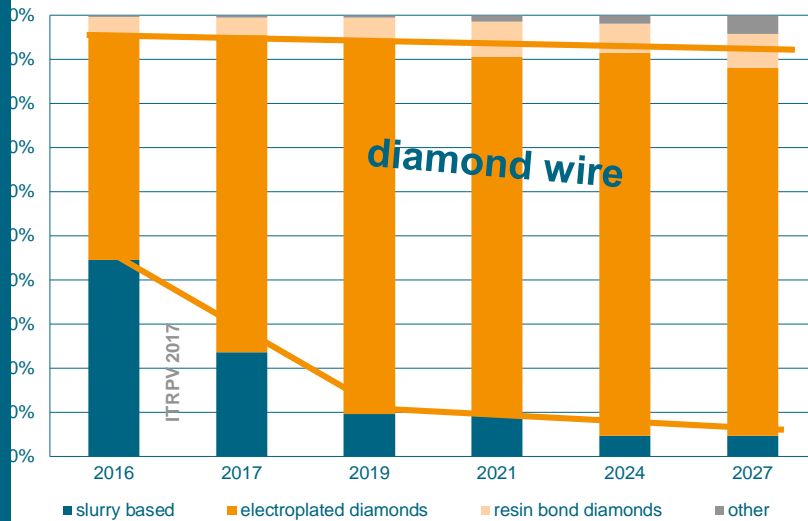
Wiring throughput DWS:

→ Fast increase by >30% expected (yellow coding)

→ Slurry sawing will drop behind

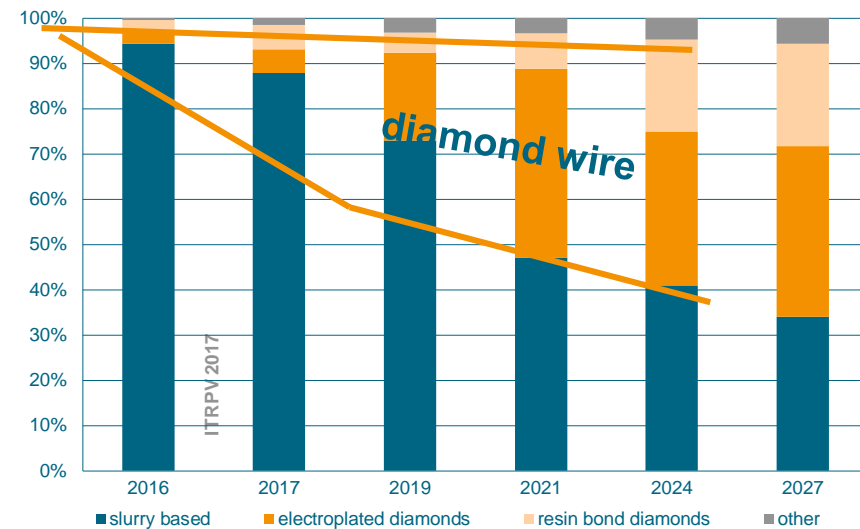
Processes: wafering technology

Trend: wafering technology for mono-Si



diamond wire wafering: now mono mainstream
 → Electroplated diamond wire is mostly used

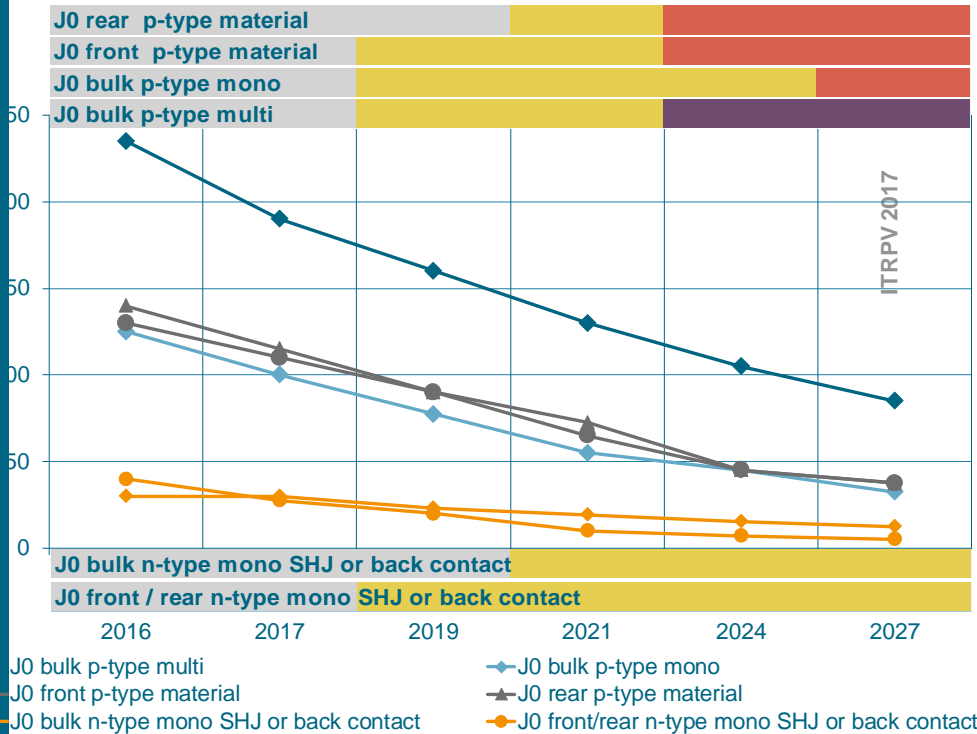
Trend: wafering technology for mc-Si



Slurry based wafering will disappear
 → change to diamond wire is ongoing
 → main challenge: texturing
 → Big progress in wet texturing
 Different Solutions compete: MCCE, Additives,....

Cell Processes - recombination current densities

Trend: $J_{0,bulk}$, $J_{0,front}$, $J_{0,rear}$



- $J_{0,bulk}$: will be further reduced optimizing requires R&D (not yet usable)

→ p-type mc-Si: **yellow** 130 → **purple** <130 fA/cm²

→ p-type mono-Si: **yellow** 60 → **red** <45 fA/cm²

N-type bulk is ready

→ n-type mono-Si: **yellow** 15 fA/cm²

- $J_{0,front} / J_{0,rear}$

→ Further reductions by >50%

But R&D required (**red coding**)

→ p-type is limited at the front side (i.e. need of improved diffusion / new pastes)

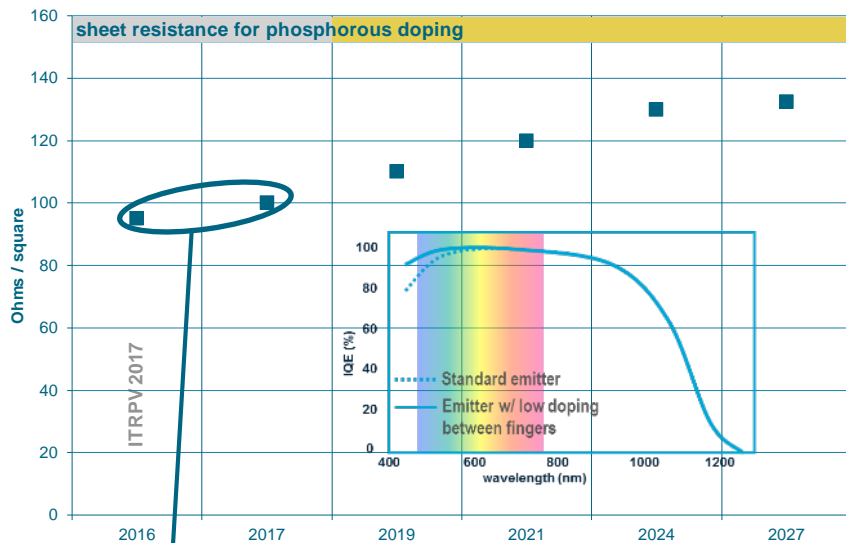
→ Wide use of rear side passivation concepts

→ p-type: reducing recombination losses is on a good way

→ n-type: overcomes p-type bulk material limitations

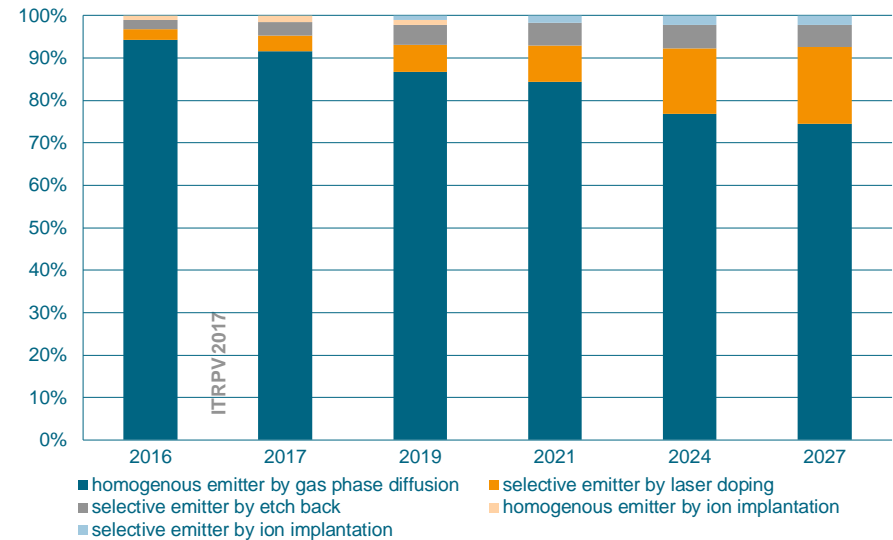
Cell – processes: emitter formation for low $J_{0\text{front}}$

Trend: emitter sheet resistance



Essential parameter for $J_{0\text{front}}$
 → 95...100 Ω/\square are standard today
 → Increase to 135 Ω/\square is predicted
 → **Challenge for tools and front pastes**

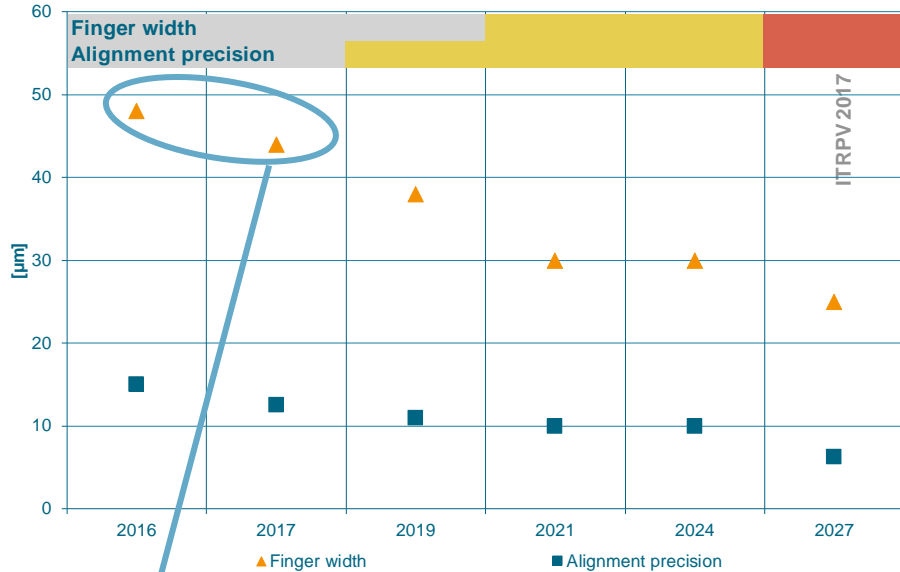
Trend: emitter formation technologies



Mainstream: homogenous gas-phase diffusion
 → selective doping: etch back or laser doping
 → Ion implant stays niche

Cell Processes: finger width / number of bus bars / bifaciality

Trend: Finger width reduction + alignment precision

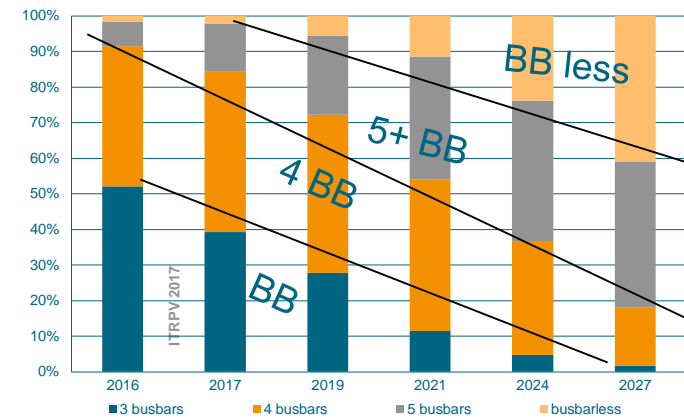


Front side grid finger width reduction continues
2017: <50µm reached!

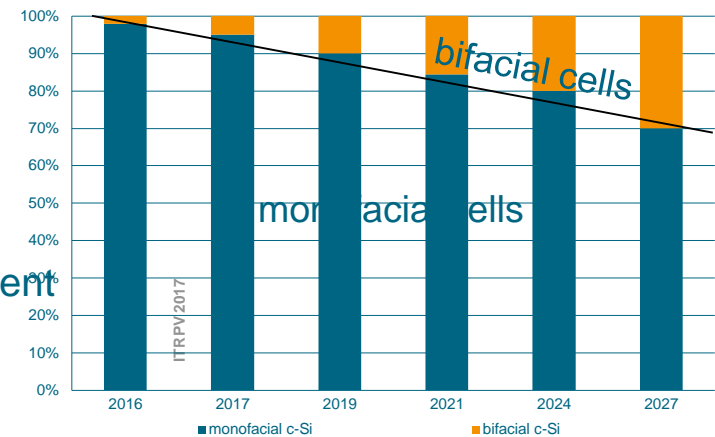
- Enables reduction of BBs + Ag reduction
- **4BB are mainstream – 3 BB will disappear**
- Alignment precision will improve to <10µm @3 sig.
- Selective emitters + Bifacial cells require good alignment
- Bifacial cells will increase market share

Improvements may proceed faster (Grey + Yellow)

Trend: number of bus bars (BB)



Trend: market share of bifacial cells

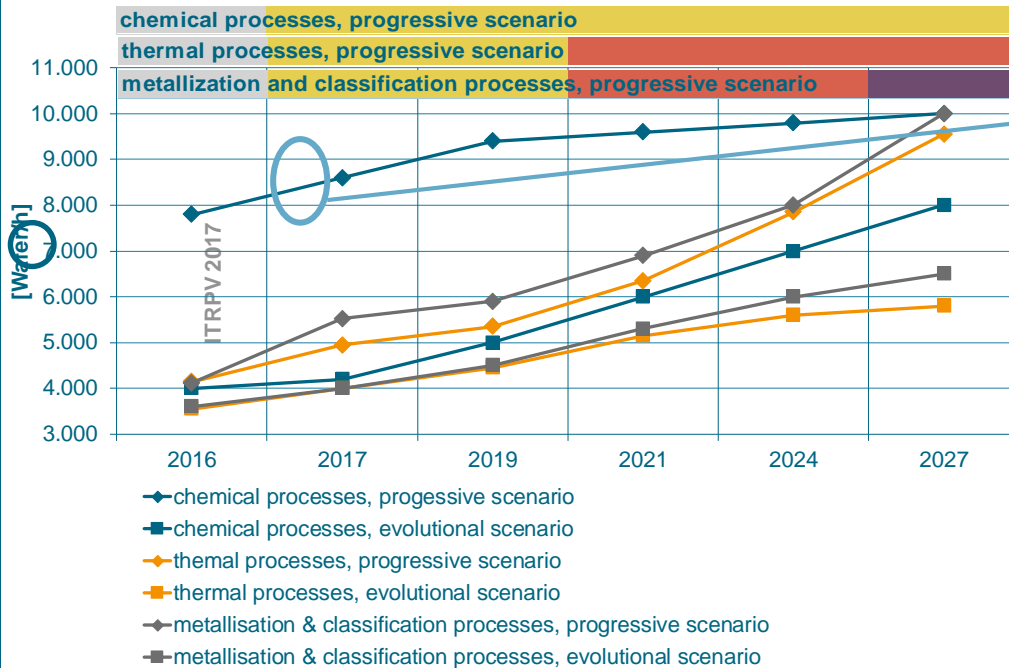


Cell – Processes: cell production tool throughputs

→ Tool throughputs will increase

ITRPV Trend:

tool throughput increase + synchronization of frontend/backend



Wet benches are leading w/ >8000 wf/h
 → Throughput increase will continue
 → Easy to implement (Grey / Yellow coding)

Challenge:
 increase throughput + Improve OEE

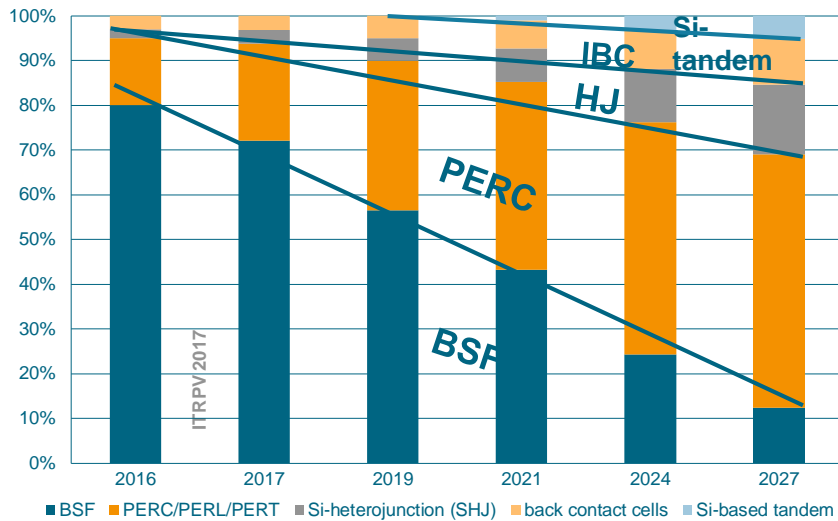
Two throughput scenarios:

Progressive = new high throughput tool

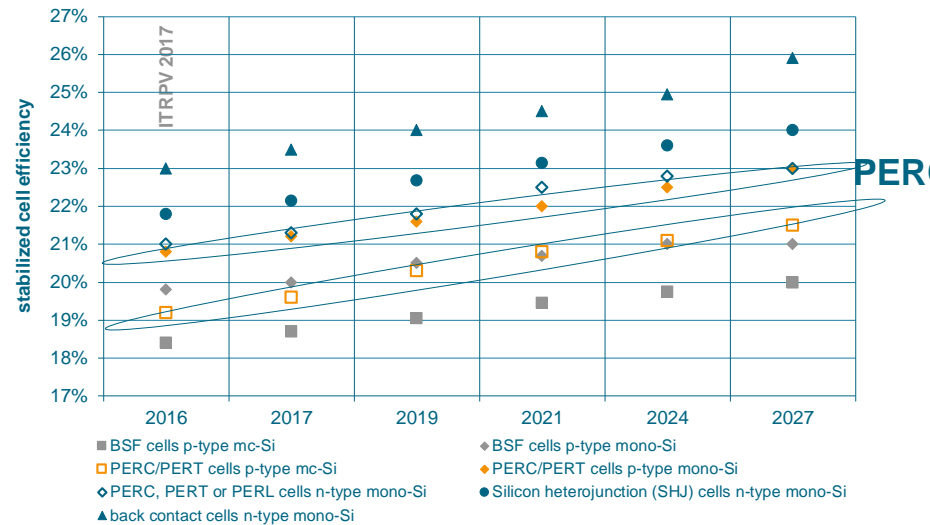
Evolutionary = Cont. improvement of tools (debottlenecking, upgrades...)

Products: cell technologies / cell efficiency trends

Trend: market share of cell concepts
2016: PERC ≈15%



Trend: stabilized cell efficiencies;
→ p-type PERC outperforms

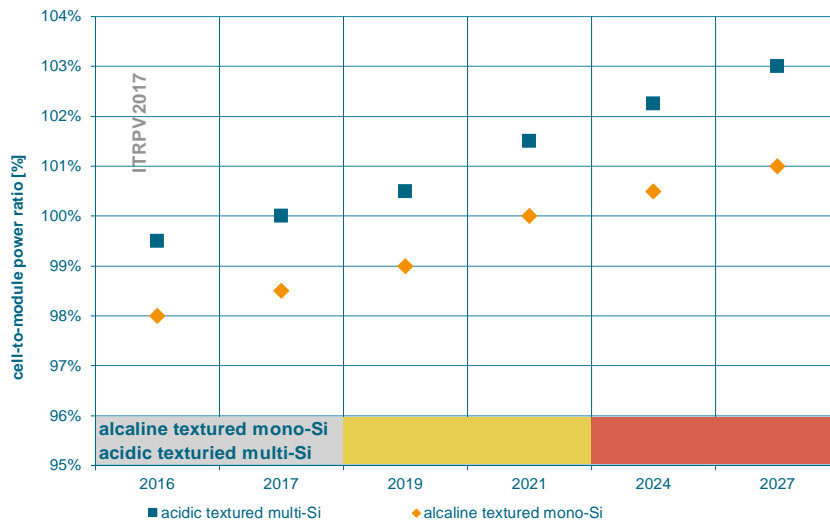


PERC is gaining market share (20% 2017)
→ BSF share is shrinking
→ Back contact + HJ: slow increasing share
→ Si tandem: under development

p-type mono PERC will reach n-type performance
mc-Si PERC is about to outperform mono BSF
→ n-type IBC + HJ for highest efficiency applications
→ stabilized >21% p-type mono PERC is in production

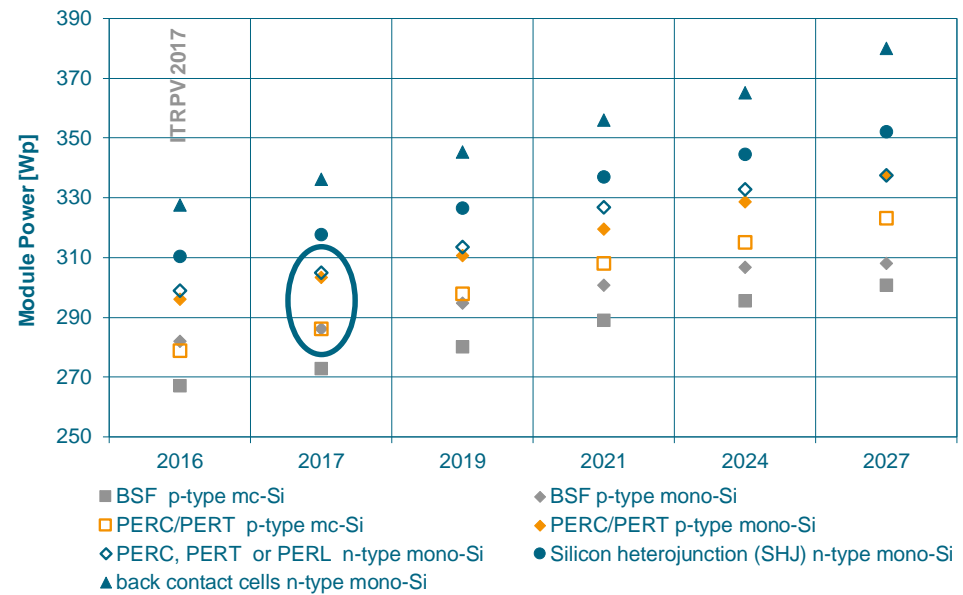
Products: module power outlook

Trend: cell to module power ratio (CTM)



CTM will increase
→ Acidic texturing has still higher CTM

Trend: module power of 60 cell (156x156mm²)

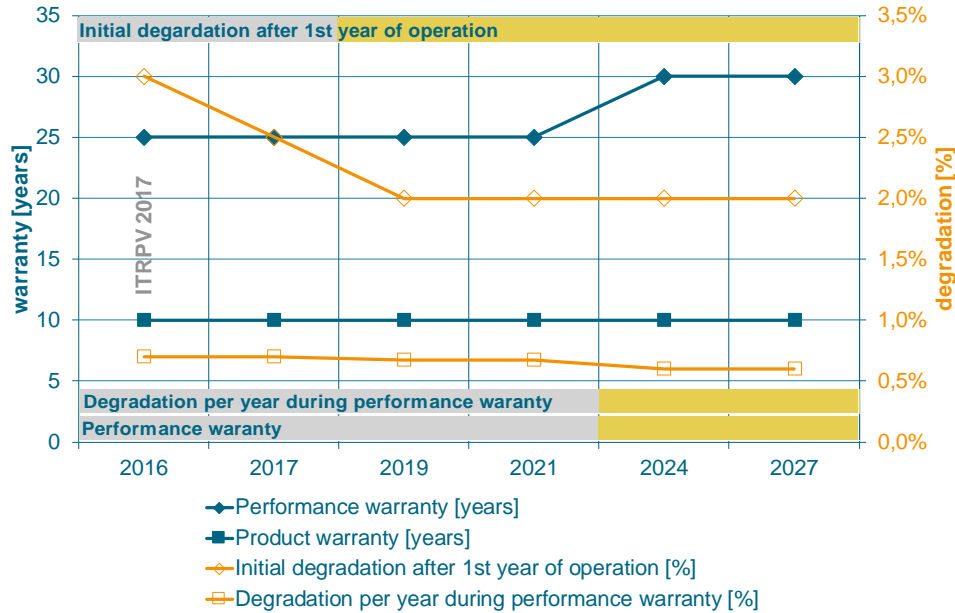


60 cell modules 2017:
Mono p-type PERC: 305 W are standard
Multi p-type PERC: 285 W are common

Products: Warranty / degradation trend



Warranty requirements & degradation for c-Si PV modules



degradation: Initial / linear/year

2016: 3.0 % / 0.7%

2017: 2.5 % / 0.68%

2019+: 2.0 % / 0.68%

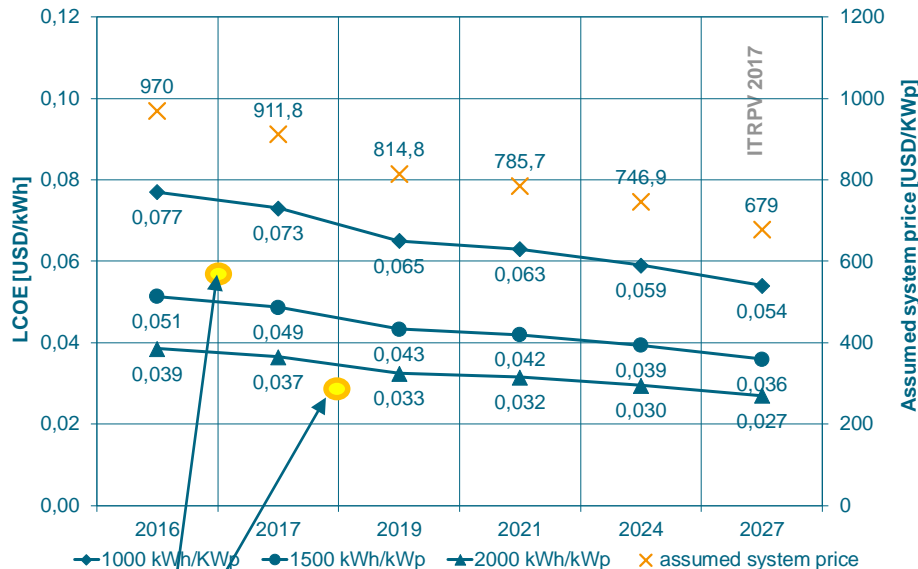
2021+: 2.0 % / 0.60%

Product warranty will remain 10 years
 Performance warranty 2024+: 30 years

Systems – Levelised Cost of Electricity (LCoE)

Trend: LCoE progress – a minimum approach

- System prices:
 - 2016: 970 \$ / kWp
 - 2027: <680 \$ / kWp



- LCoE
 - 2016: 3.9 8 \$ct/kWh (GER avg. 7.7 \$ct**)
 - 2027: 2.7 5 \$ct/kWh are realistic
- System live times 25 years are assumed
- Next steps to further reduce LCoE:
 - extended service live to 30 years (supported by performance warranty trend)
 - further efficiency improvements + cost down measures

LCoE depends strongly on local conditions

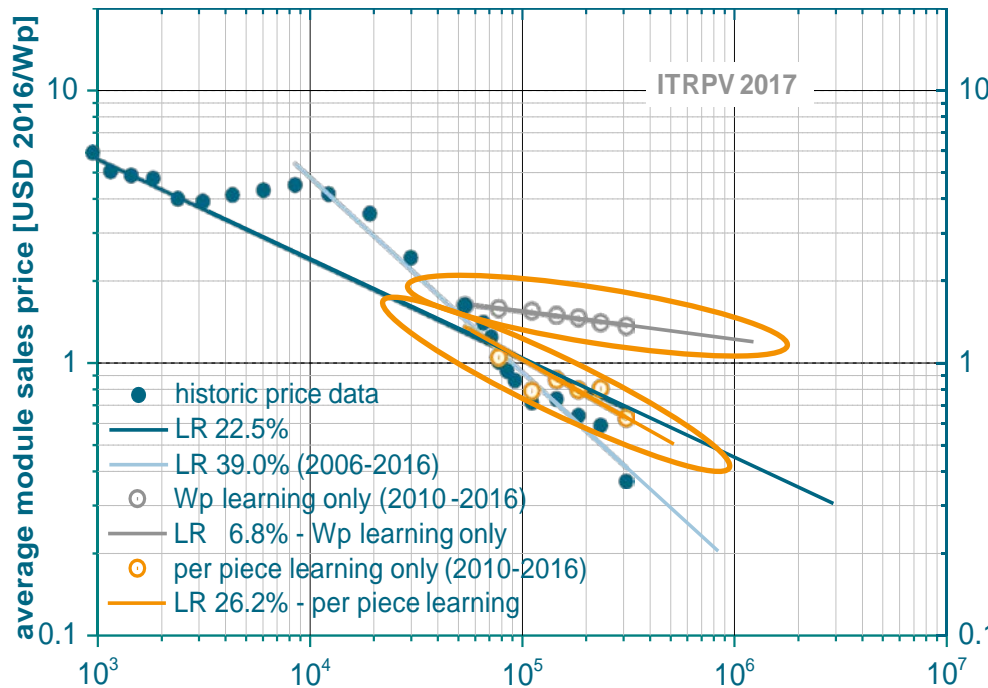
- ~5.7 US\$ct/kWh lowest auction bidder in GER 2016** (avg. 7.7\$ct)
- ~2.42 US\$ct/kWh possible near Abu Dhabi* today

* <http://www.pv-tech.org/news/jinkosolar-in-deal-to-build-1.2GWp-solar-plant-in-Abu-Dhabi>

** <http://www.sunwindenergy.com/photovoltaics/danish-bidders-win-cross-border-pv-tender>

Outlook: in detail look at PV learning curve

1976-2016: LR= 22.5%
 2006-2016: LR= 39.0%



ITRPV finding:

2010-2016 Wp and per piece learning analysis revealed:

Wp learning ~ 7% (continually)
per piece learning ~26% (market driven)

conclusion:

→ Learning was and will be always a combination of

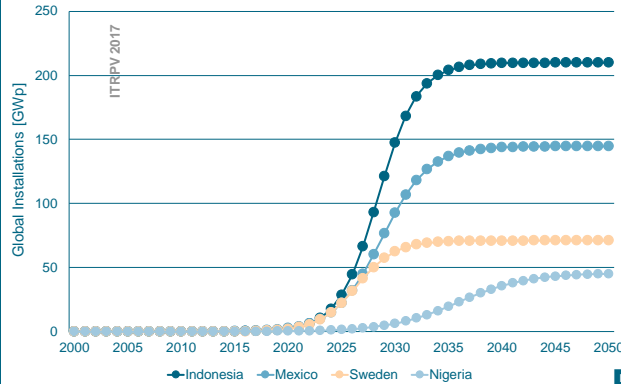
efficiency increase
+ continues cost reduction per piece
= cost reduction of PV generated electricity

→ Wp increase w/o cost increases /Wp

→ But how will PV proceed in future?
Approach: logistic growth

PV market trend until 2050: logistic growth

Approach: 3 cases for 190 different countries in 4 regions
Asia / America / Africa / EU



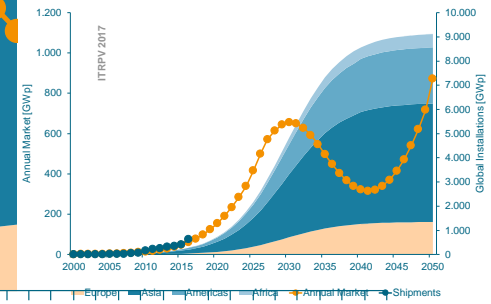
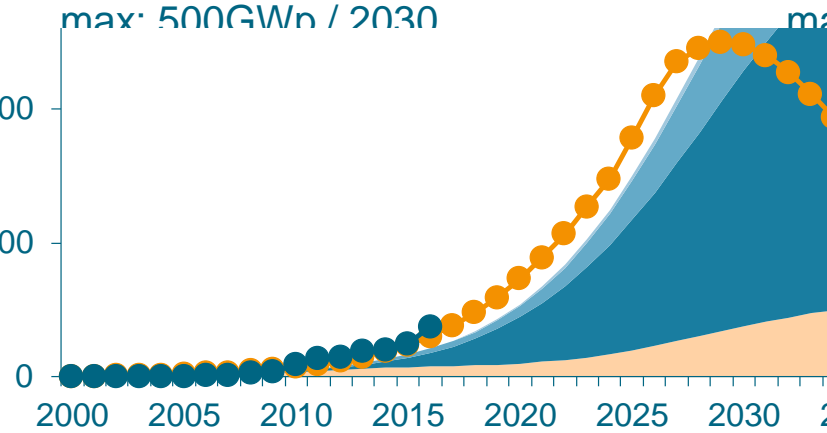
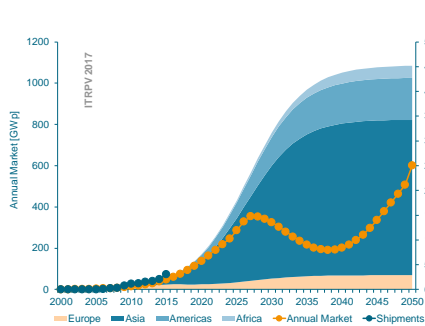
ITRPV finding:

- Shipments until 2016: slightly above all scenarios
- Yearly PV market: 335 GWp 600 GWp
→ Current technology may run all scenarios
→ Replacement rate = key to overcome down cycles



PV has a bright future – ITRPV provides a guideline

low: 4.5 TWp/7 PWh (16% of el. energy) medium: 6.8 TWp/10.6 PWh (+ prim. en.) high: 9.2 TWp/ 14.3 PWh (++) prim. en.)
Max:355GWp / 2027 max: 500GWp / 2030 max:600GWp / 2025



Summary

Talk provided:

- Idea about market expectations and status
- Discussion of ITRPV 8th edition findings and maturity report update

Outlook:

- PV market is and will remain extremely cost sensitive
 - PV market will further increase (turbulently) in the years to come!
 - Silicon-PV will stay dominant during the next years
 - Production capacities will (and have to) increase further
 - Quality is key for continued success of PV
- **Manufacturers, Suppliers and Customers will benefit from growing PV market**
- **But all players have to be flexible and innovative**

